



# R&E International

A Subsidiary of Microchip Technology Inc.

## RE46C152

CMOS Ionization Smoke Detector ASIC with Interconnect, Timer Mode and Tone Select

Product Specification

### General Description

The RE46C152 is a low power CMOS ionization type smoke detector IC. With few external components this circuit will provide all the required features for an ionization type smoke detector.

An internal oscillator strobes power to the smoke detection circuitry for 10.5mS every 1.66 seconds to keep standby current to a minimum. A check for a low battery condition is performed every 40 seconds when in standby. The Tone input allows for selection of a temporal pattern or a 2/3 duty cycle continuous tone. The temporal horn pattern supports the NFPA 72 emergency evacuation signal.

An interconnect pin allows multiple detectors to be connected such that when one units alarms all units will sound.

An internal 8 minute timer allows for a separate button to be used for reduced sensitivity mode. Single button operation for test and timer mode is also possible.

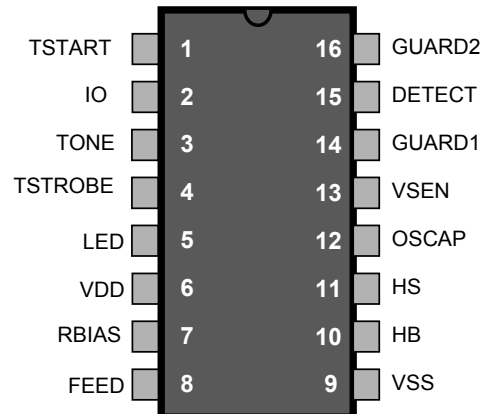
Although this device was designed for smoke detection utilizing an ionization chamber it could be used in a variety of security applications.

Utilizing low power CMOS technology the RE46C152 was designed for use in smoke detectors that comply with Underwriters Laboratory Specification UL217 and UL268.

### Features

- >1500V ESD Protection (HBM) on all Pins
- Guard Outputs for Ion Detector Input
- +/-0.75pA Detect Input Current
- Internal Reverse Battery Protection
- Low Quiescent Current Consumption (<6.5uA)
- 16L PDIP
- Internal Low Battery Detection
- Power Up Low Battery Test
- Interconnect up to 40 Detectors
- Pin selectable horn patterns
- 8 Minute Timer for Sensitivity Control
- Available in RoHS Compliant Pb Free Packaging.

### Pin Configuration



### ABSOLUTE MAXIMUM RATINGS

#### PARAMETER

Supply Voltage  
Input Voltage Range Except FEED, IO  
FEED Input Voltage Range  
IO Input Voltage Range  
Reverse Battery Time  
Input Current except FEED  
Operating Temperature  
Storage Temperature  
Maximum Junction Temperature

#### SYMBOL

$V_{DD}$   
 $V_{in}$   
 $V_{infd}$   
 $V_{io1}$   
 $T_{RB}$   
 $I_{in}$   
 $T_A$   
 $T_{STG}$   
 $T_J$

#### VALUE

15  
-.3 to  $V_{dd} + .3$   
-10 to +22  
-.3 to 17  
5  
10  
-10 to 60  
-55 to 125  
150

#### UNITS

V  
V  
V  
V  
S  
MA  
°C  
°C  
°C

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and operation at these conditions for extended periods may affect device reliability.

This product utilizes CMOS technology with static protection; however proper ESD prevention procedures should be used when handling this product. Damage can occur when exposed to extremely high static electrical charge.

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**DC Electrical Characteristics at TA = 25°C, VDD=9V, OSCAP=.1uF, RBIAS=8.2MΩ, VSS=0V (unless otherwise noted)**

Parameter	Symbol	Test Pin	Test Conditions	Limits			
				Min	Typ	Max	Units
Supply Voltage	V <sub>DD</sub>	6	Operating	6		12	V
Supply Current	I <sub>DD1</sub>	6	RBIAS=8.2MΩ, OSCAP=.1uF		5	6.5	uA
	I <sub>DD2</sub>	6	RBIAS=8.2MΩ, OSCAP=.1uF; Vdd=12V			9	uA
Input Voltage High	V <sub>IH1</sub>	3,8		6.2	4.5		V
	V <sub>IH2</sub>	2	No Local Alarm, IO as an Input	3			V
	V <sub>IH3</sub>	1		4.5			V
Input Voltage Low	V <sub>IL1</sub>	3,8			4.5	2.7	V
	V <sub>IL2</sub>	2	No Local Alarm, IO as an Input			1	V
	V <sub>IL3</sub>	1				2.5	V
Input Leakage Low	I <sub>LDET1</sub>	15	VDD=9V, DETECT=VSS, 0-40% RH			-0.75	pA
	I <sub>LDET2</sub>	15	VDD=9V, DETECT=VSS, 85% RH Note 1			-1.50	pA
	I <sub>LD</sub>	8	FEED=-10V			-50	uA
Input Leakage High	I <sub>HDET1</sub>	15	VDD=9V, DETECT=VDD, 0-40% RH			0.75	pA
	I <sub>HDET2</sub>	15	VDD=9V, DETECT=VDD, 85% RH Note 1			1.50	pA
	I <sub>HD</sub>	8	FEED=22V			50	uA
	I <sub>IOL2</sub>	2	No Alarm, Vio=17V			150	uA
Output Off Leakage High	I <sub>IOHZ</sub>	4,5	Outputs Off			1	uA
Input Pull Up Current	I <sub>PU1</sub>	3	TONE=VSS, RBIAS=8.2MΩ	-50		-800	nA
Input Pull Down Current	I <sub>PD1</sub>	1	TSTART=9V	20	50	80	uA
Output High Voltage	V <sub>OH1</sub>	10,11	IOH=-16mA, VDD=7.2V	6.3			V
Output Low Voltage	V <sub>OL1</sub>	10,11	IOL=16mA, VDD=7.2V			.9	V
	V <sub>OL2</sub>	4	IOL=500ua			.5	V
	V <sub>OL3</sub>	5	IOL=10mA, VDD=7.2V			1	V
Output Current	I <sub>IOL1</sub>	2	No Alarm, Vio=Vdd-2V	25		60	uA
	I <sub>IOH1</sub>	2	Alarm, Vio=Vdd-2V or Vio=0V	-4		-16	mA
	I <sub>IODMP</sub>	2	At Conclusion of Local Alarm or Test, Vio=1V	5			mA
Low Battery Voltage	V <sub>LB</sub>	6	T <sub>A</sub> =-10 to 60°C, Note 3	7.2	7.5	7.8	V
Internal Sensitivity Set Voltage	V <sub>SET1</sub>	13		48.5	50	51.5	%V <sub>DD</sub>
	V <sub>SET2</sub>						

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## DC Electrical Characteristics – Continued

Parameter	Symbol	Test Pin	Test Conditions	Limits			
				Min	Typ	Max	Units
Offset Voltage	VG <sub>OS1</sub>	14,15	Guard Amplifier	-50		50	mV
	VG <sub>OS2</sub>	15,16	Guard Amplifier	-50		50	mV
	VG <sub>OS3</sub>	13,15	Smoke Comparator	-50		50	mV
Common Mode Voltage	V <sub>CM1</sub>	14,15	Guard Amplifier, Note 2	2		V <sub>DD</sub> -5	V
	V <sub>CM2</sub>	13,15	Smoke Comparator, Note 2	.5		V <sub>DD</sub> -2	V
Output Impedance	Z <sub>OUT</sub>	14,16	Guard Amplifier Outputs, Note 2		10		kΩ
Hysteresis	V <sub>HYS</sub>	13	No Alarm to Alarm Condition	90	130	170	mV

Note 1: Sample test only.

Note 2: Not 100% production tested.

Note 3: Production test at room with temperature guardbanded limits.

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**AC Electrical Characteristics at TA = 25°C, VDD=9V, OSCAP=.1uF, RBIAS=8.2MΩ, VSS=0V (unless otherwise noted)**

Parameter	Symbol	Test Pin	Test Conditions	Limits			
				Min	Typ	Max	Units
Oscillator Period	T <sub>PER1</sub>	12	No Alarm Condition	1.34	1.67	2	S
	T <sub>PER2</sub>	12	Alarm Condition	37.5	41.5	45.8	mS
Oscillator Pulse Width	T <sub>PW</sub>	5	Operating	9.4	10.5	12.9	mS
LED On Time	T <sub>LON</sub>	5	Operating	9.4	10.5	12.9	mS
LED Off Time	T <sub>LOF1</sub>	5	Standby, No Alarm	32	40	48	S
	T <sub>LOF2</sub>	5	Alarm Condition	.8	1	1.2	S
	T <sub>LOF3</sub>	5	Timer Mode, No Alarm	8	10	12	S
Horn On Time	T <sub>HON1</sub>	10,11	Operating, Alarm Condition, Note 4 Tone = VDD or Float	450	500	550	mS
	T <sub>HON2</sub>	10,11	Low Battery, No Alarm	9.4	10.5	12.9	mS
	T <sub>HON3</sub>	10,11	Operating, Alarm Condition, TONE=Low	150	166	183	mS
Horn Off Time	T <sub>HOF1</sub>	10,11	Operating, Alarm Condition, Note 4 Tone = VDD or Float	450	500	550	mS
	T <sub>HOF2</sub>	10,11	Operating, Alarm Condition, Note 4 Tone = VDD or Float	1.35	1.5	1.65	S
	T <sub>HOF3</sub>	10,11	Operating, Alarm Condition, TONE=Low	75	83	92	mS
	T <sub>HOF4</sub>	10,11	Low Battery, No Alarm	32	40	48	S
IO Charge Dump Duration	T <sub>IODMP</sub>	2	At Conclusion of Local Alarm or Test	1.34	1.67	2.0	S
IO Delay	T <sub>IODLY1</sub>	2	From Start of Local Alarm Condition to IO Active		No Delay		S
IO Filter	T <sub>IOFILT</sub>	2	IO pulse width guaranteed to be filtered. IO as Input, No Local Alarm			450	mS
Remote Alarm Delay	T <sub>IODLY2</sub>	2	No Local Alarm, IO as input, From IO active to Horn Active	.450		2.2	S
Timer Period	T <sub>TPER</sub>	4	No Alarm	6.2	8	9.8	Min

Note 4 – See timing diagram for horn temporal pattern.  
All timing except for T<sub>PER</sub> and T<sub>PW</sub> are guaranteed by functional tests.

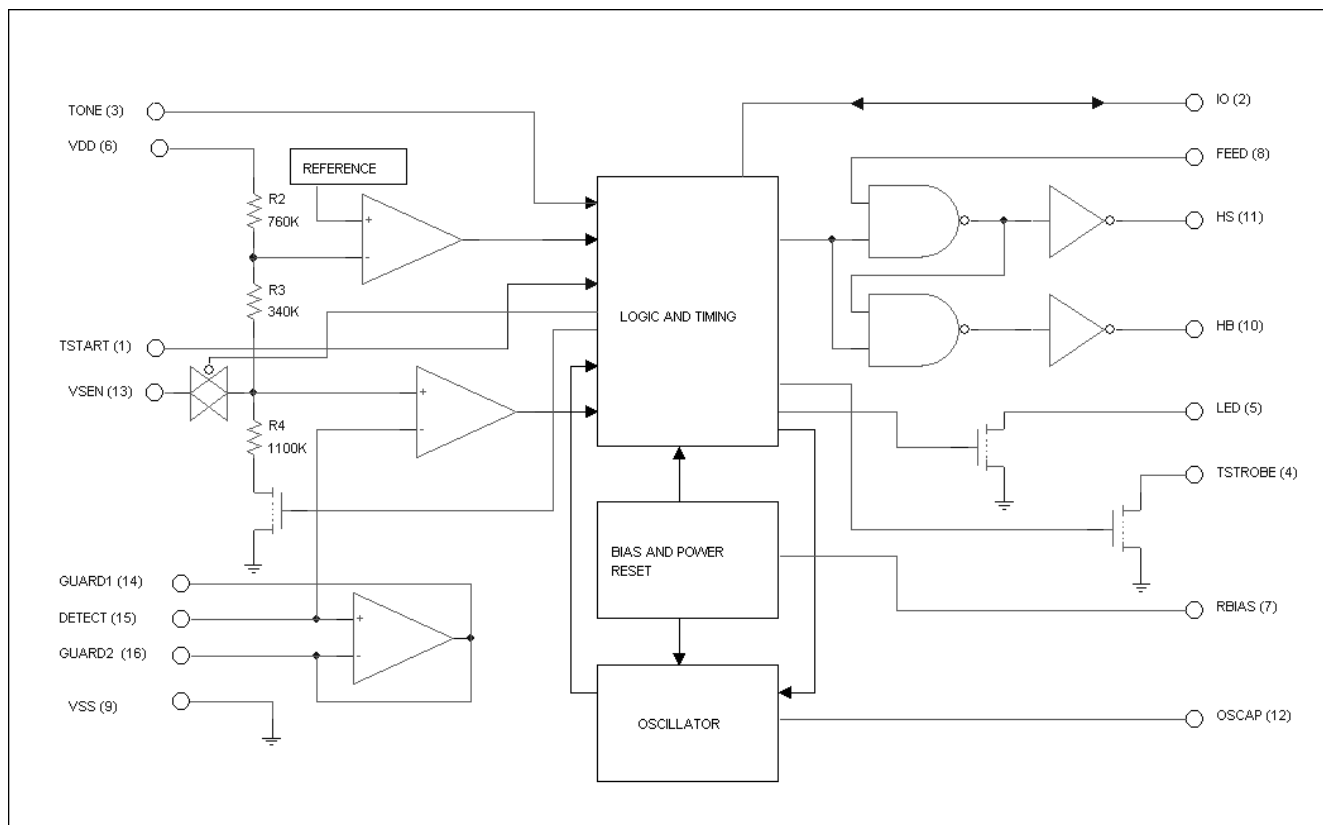
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## Functional Block Diagram



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## DEVICE DESCRIPTION and APPLICATION NOTES

**Internal Timing** – With external components as indicated on the application drawing the period of the oscillator is nominally 1.67 seconds in standby. Every 1.66 seconds the detection circuitry is powered up for 10.5mS and the status of the smoke comparator is latched. In addition every 40 seconds the LED driver is turned on for 10.5mS and the status of the low battery comparator is latched. The smoke comparator status is not checked during the low battery test, during the low battery horn warning chirp, or when the horn is on due to an alarm condition.

If an alarm condition is detected the oscillator period increases to 41.5mS.

Due to the low currents used in the oscillator the capacitor on pin 12 should be a low leakage type. Oscillator accuracy will depend mainly on the tolerance of the RBIAS resistor and OSCAP capacitor.

**Smoke Detection Circuit** – The smoke comparator compares the ionization chamber voltage to a voltage derived from a resistor divider across VDD. This divider voltage is available externally on pin 13 (VSEN). When smoke is detected this voltage is internally increased by 130mV nominal to provide hysteresis and make the detector less sensitive to false triggering.

Pin 13 (VSEN) can be used to modify the internal set point for the smoke comparator by use of external resistors to VDD or VSS. Nominal values for the internal resistor divider are indicated on the block diagram. These internal resistor values can vary by up to  $\pm 20\%$  but the resistor matching should be  $< 2\%$  on any one device.

The guard amplifier and outputs are always active and will be within 50mV of the DETECT input to reduce surface leakage. The guard outputs also allow for measurement of the DETECT input without loading the ionization chamber.

**Low Battery Detection** – An internal reference is compared to the voltage divided VDD supply. The battery can be checked under load via the LED low side driver output since low battery status is latched at the end of the 10.5mS LED pulse. A Transmission switch on VSEN prevents any interaction from external adjustment resistance during the low battery test

**LED Pulse** – The LED is pulsed on for 10.5mS every 40S in standby. In alarm the LED is pulsed on for 10.5mS every 1S.

**Interconnect** – Pin 2 (IO) provides the capability to common many detectors in a single system. If a single unit goes into alarm the IO pin is driven high. This high signal causes the interconnected units to alarm. The LED flashes every 1S for 10.5mS on the signaling unit and is inhibited on the units that are in alarm due to the IO signal. An internal sink device on the IO pin helps to discharge the interconnect line. This charge dump device is active for 1 clock cycle after the unit exits the alarm condition (1.67S).

The interconnect input has a 500mS nominal digital filter. This allows for interconnection to other types of alarms (carbon monoxide for example) that may have a pulsed interconnect signal.

**Testing** – At power up all internal registers are reset. The low battery set point can be tested at power up by holding FEED and OSCAP low at power up. HB will change state as VDD passes through the low battery set point. By holding pin 12 (OSCAP) low the internal power strobe is active. Functional testing can be accelerated by driving pin 12 with a 4kHz square wave however the 10.5mS strobe period must be maintained for proper operation of the analog circuitry. Please refer to the timing diagrams.

**Timer Mode** – The transition of pin 1 (TSTART) from a high to low level initiates an eight minute timer. During this 8 minute period the open drain NMOS on pin 4 (TSTROBE) is strobed on with the internal clock. A resistor connected to this pin could be used to modify the detector sensitivity for the timer period.

**Horn Tone** – Pin 3 selects the NFPA72 horn tone (high or floating) or the 2/3 duty cycle continuous tone (low). If this pin is externally connected high, use a current limiting resistor from pin 3 to VDD.

**Reverse Battery Protection** – The RE46c152 internally limits the current from VSS to VDD in the event of accidental polarity reversal. If an input is connected to VDD it should be done through a resistance of at least 1.5K to limit the reverse current through this path.

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Typical Application – 2 Buttons Operation, Temporal Horn Pattern

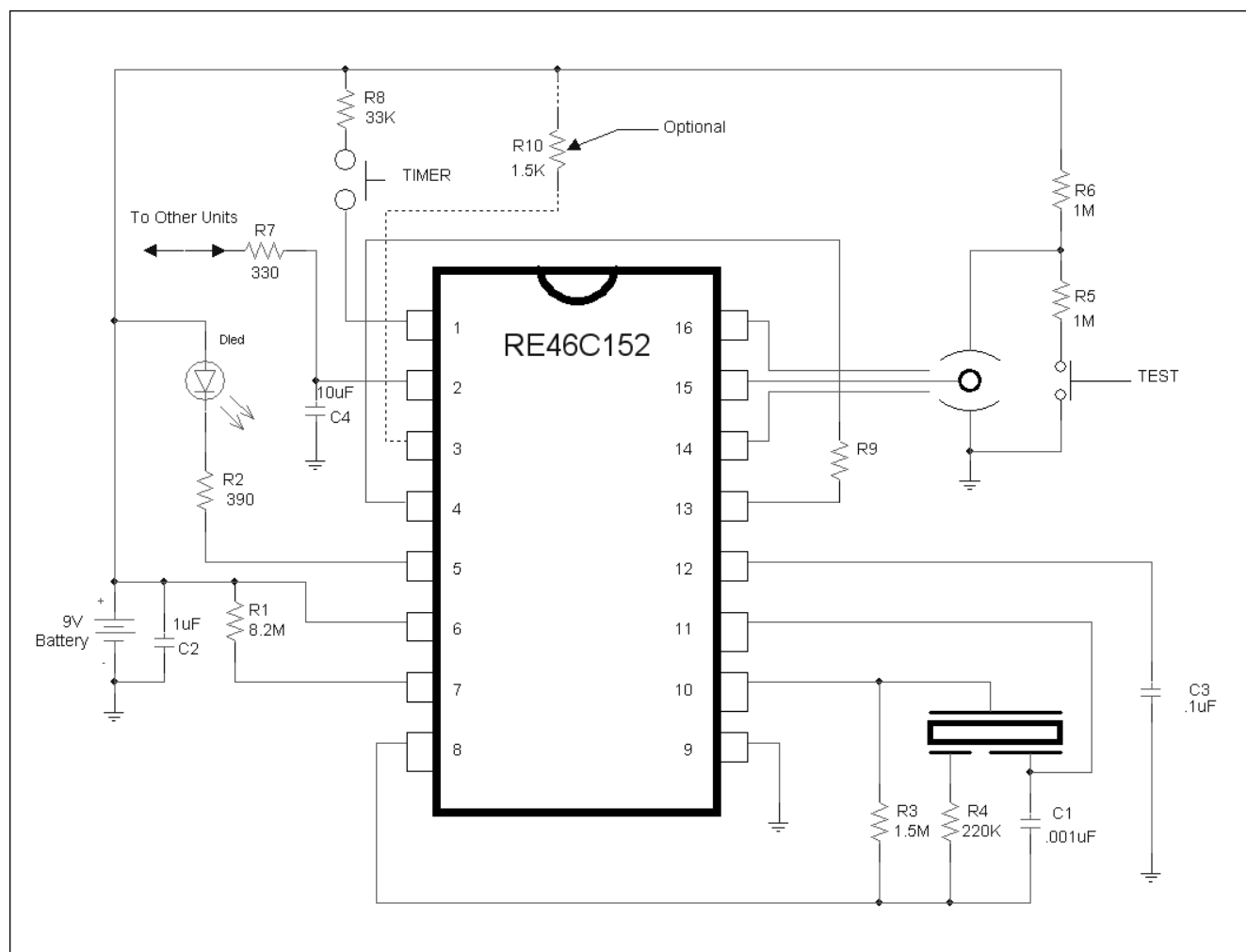


Figure 2

## Notes for Application Drawing Figure 2:

Select R9 to reduce sensitivity during the timer mode.

R3, R4 and C1 are typical values and may be adjusted to maximize sound pressure.

C2 should be located as close as possible to the device power pins.

Route the pin 8 PC board trace away from pin 7 to avoid coupling.

If used R10 is 1.5K minimum

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### Typical Application – 1 Button Operation, Temporal Horn Pattern

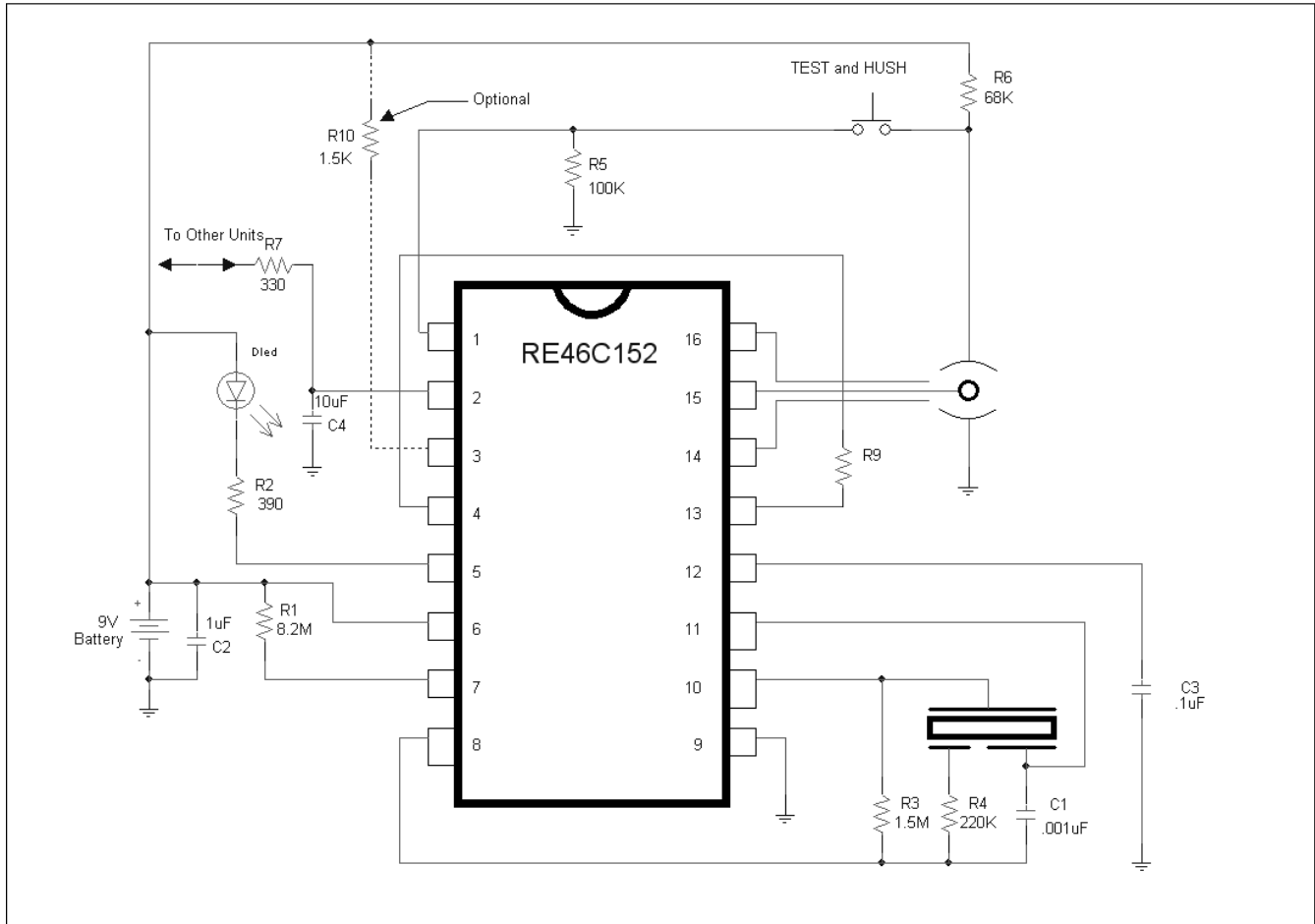


Figure 3

### Notes for Application Drawing Figure 3:

Select R5 and R6 values for the correct level to test the ion chamber. The voltage level at the TSTART input (pin 1) must be greater than the minimum VIH level to initiate the timer mode. Pin 1 has an internal 180K nominal pull down which must be considered.

Select R9 to reduce sensitivity during the timer mode.

R3, R4 and C1 are typical values and may be adjusted to maximize sound pressure.

C2 should be located as close as possible to the device power pins.

Route the pin 8 PC board trace away from pin 7 to avoid coupling.

If used R10 is 1.5K minimum



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### Typical Application – 2 Button Operation – 2/3 Duty Cycle Continuous Tone Horn Pattern

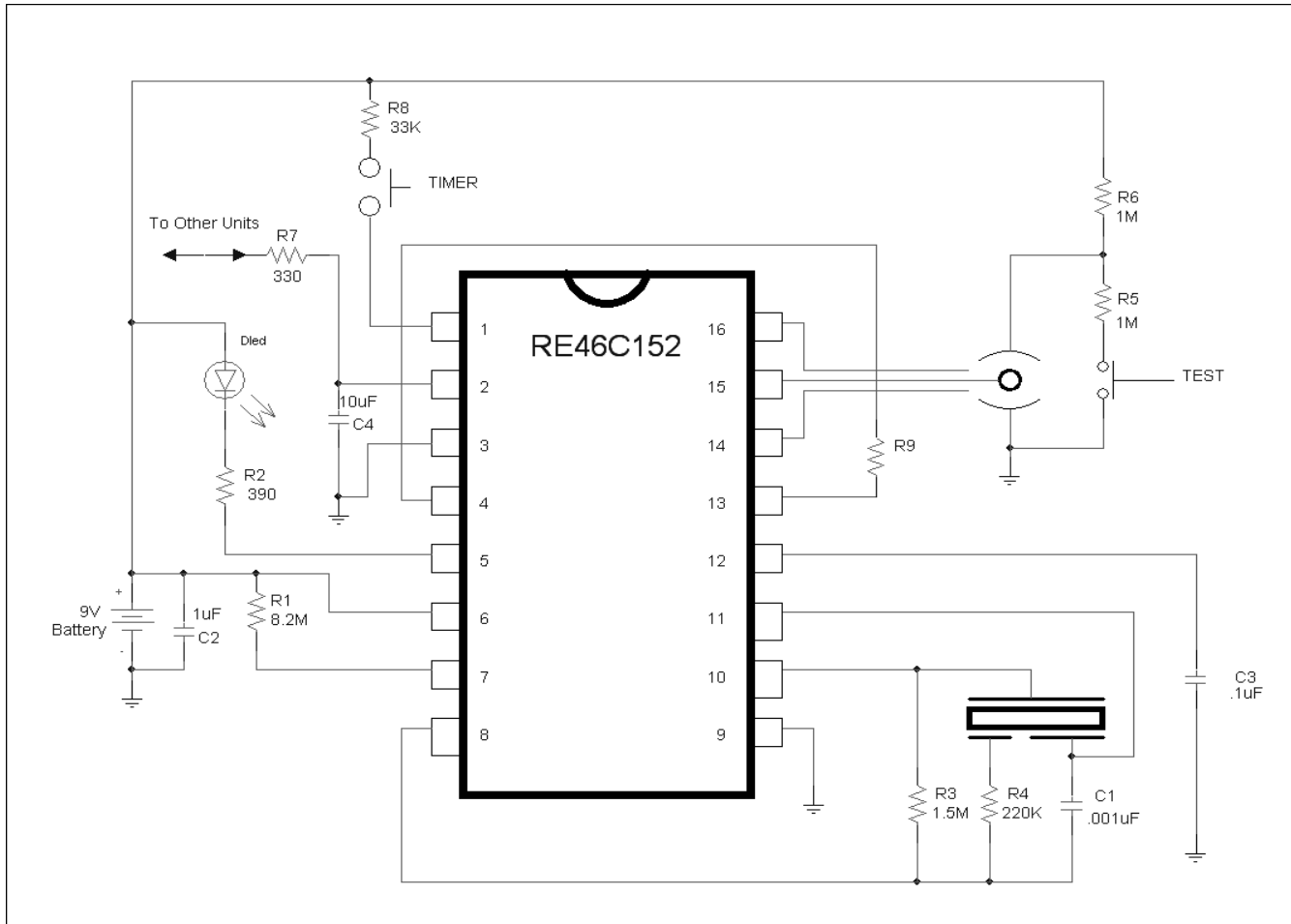


Figure 4

Notes for Application Drawing Figure 4:

Select R5 and R6 values for the correct level to test the ion chamber. The voltage level at the TSTART input (pin 1) must be greater than the minimum VIH level to initiate the timer mode. Pin 1 has an internal 180K nominal pull down which must be considered.

Select R9 to reduce sensitivity during the timer mode.

R3, R4 and C1 are typical values and may be adjusted to maximize sound pressure.

C2 should be located as close as possible to the device power pins.

Route the pin 8 PC board trace away from pin 7 to avoid coupling.

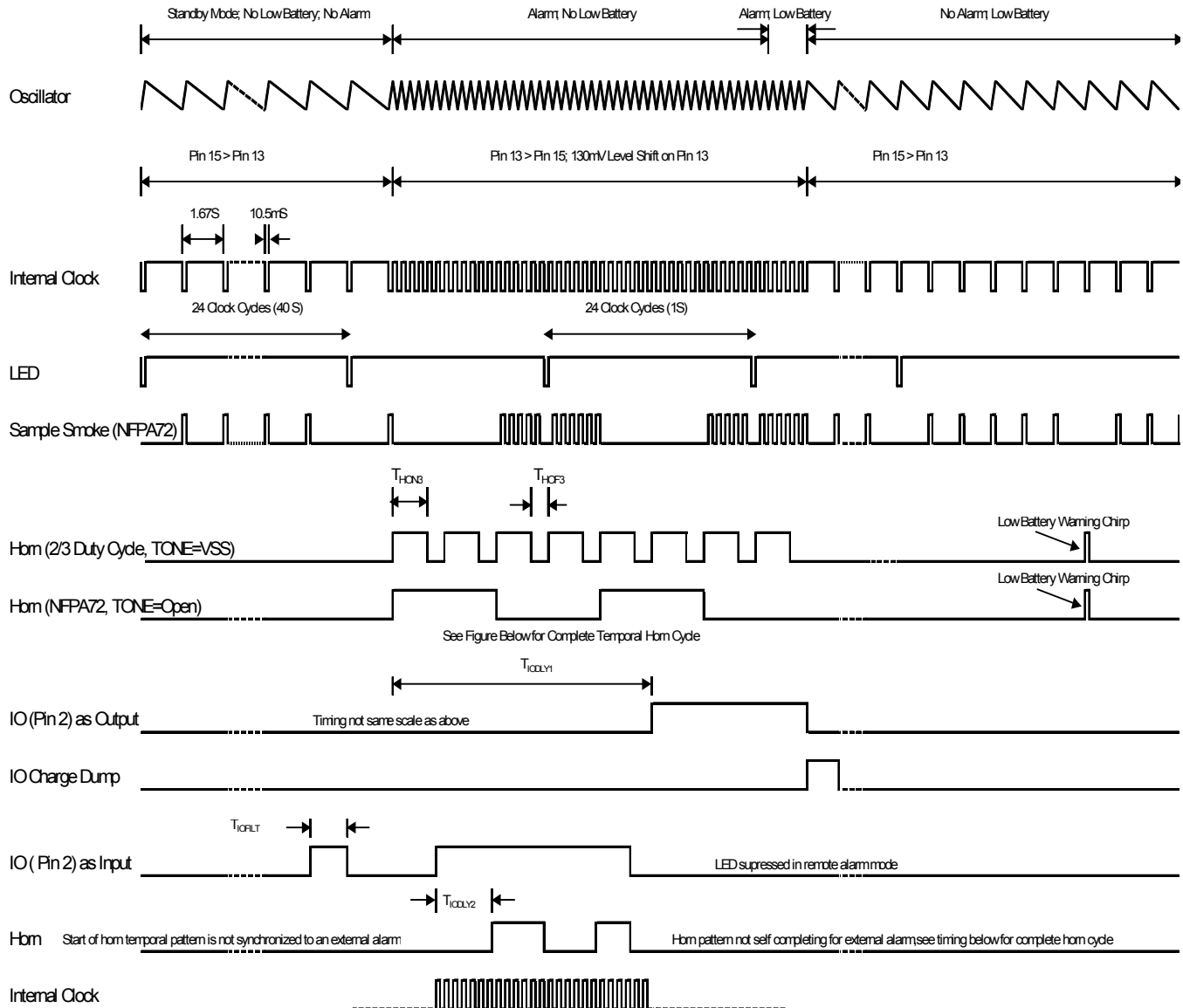
# RE46C152

**CMOS Ionization Smoke Detector ASIC with Interconnect,  
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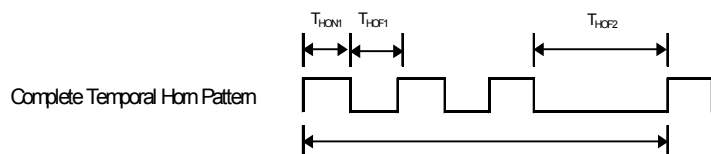
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## Timing Diagram (non Timer Mode)



### Notes:

1. Smoke is not sampled when the horn is active. Horn cycle is self completing in local alarm.
2. Low battery warning chirp is suppressed in local or remote alarm
3. IO Dump active only in local alarm, inactive if external alarm



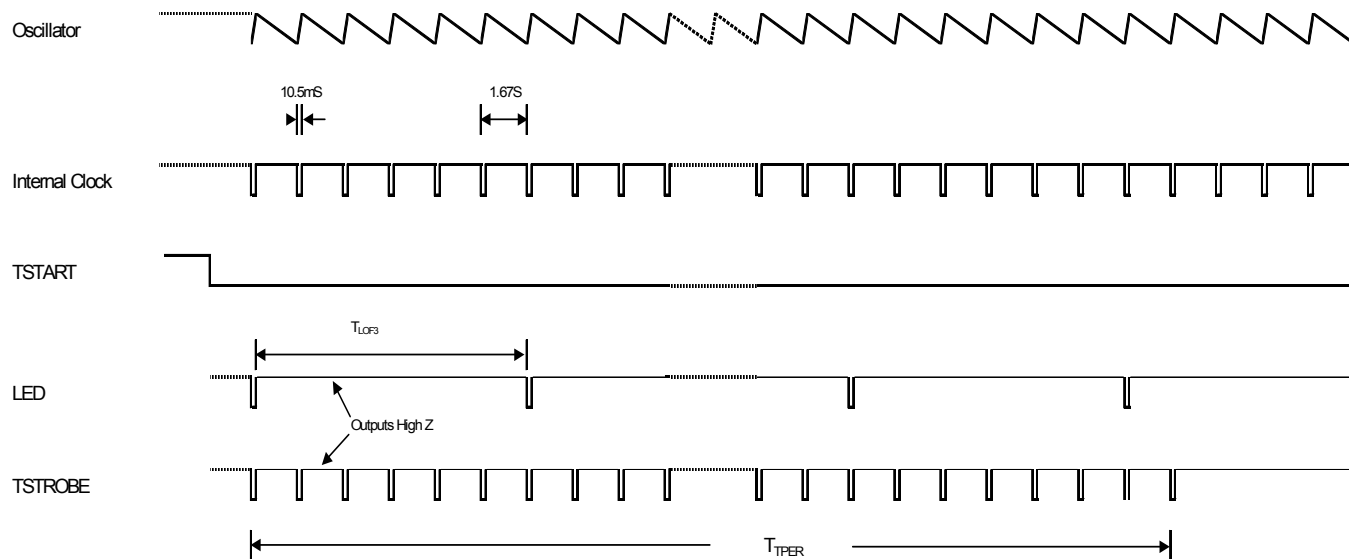
# RE46C152

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Timing Diagram (Timer Mode)



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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

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moschip.ru\_6

moschip.ru\_9